
	<p><b>SI3981DV-T1-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3981DV-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET 2P-CH 20V 1.6A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3981DV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 70417 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI3981DV-T1-E3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET 2P-CH 20V 1.6A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	70417 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	800mW
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.6A
Rds On (Max) @ Id, Vgs	185 mOhm @ 1.9A, 4.5V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI3981DV-T1-E3 ist neu im Original, Suche SI3981DV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3981DV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3981DV-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>SI3981DV0-T1-E3</b> VISHAY VISHAY SOT-23	 <b>SI3983DV-T1-E3</b> Vishay / Siliconix MOSFET 2P-CH 20V 2.1A 6-TSOP	 <b>SI3973DV-T1-E3</b> VISHAY VISHAY TSOP-6	 <b>SI3981DV-T1-GE3</b> Vishay / Siliconix MOSFET 2P-CH 20V 1.6A 6-TSOP
 <b>SI3971DV-T1-E3</b> V V TSOP-6	 <b>SI3981DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 1.6A 6-TSOP	 <b>SI3973DV-T1-GE3</b> VISHAY VISHAY TSOP-6	 <b>SI3981DV</b> Vishay Precision Group SI3981DV Vishay

### heiße Teile

Mehr

 SI3900DV-T1-E3	 SI3900DV-T1-E3	 SI3900DV-T1-GE3	 SI3900DV-T1-GE3	 SI3905DV-T1
 SI3905DV-T1-E3	 SI3905DV-T1-E3	 SI3905DV-T1-GE3	 SI3905DV-T1-GE3	 SI3909DV-T1
 SI3909DV-T1-E3	 SI3909DV-T1-E3	 SI3909DV-T1-GE3	 SI3909DV-T1-GE3	 SI3911DV
 SI3911DV-T1	 SI3911DV-T1-E3	 SI3911DV-T1-E3	 SI3911DV-T1-G33	 SI3911DV-T1-GE3
 SI3911DV-T3-E3	 SI3915DV	 SI3915DV-T1-E3	 SI3915DV-T1-GE3	 SI3932DV-T1-GE3
 SI3932DV-T1-GE3	 SI3948DV-T1	 SI3948DV-T1-E3	 SI3948DV-T1-E3	 SI3948DV-T1-GE3
 SI3948DV-T1-GE3	 SI3951-KU	 SI3951DV-T1-E3	 SI3951DV-T1-E3	 SI3951DV-T1-GE3
 SI3951DV-T1-GE3	 SI3981DV-T1-E3	 SI3981DV-T1-GE3	 SI3981DV-T1-GE3	 SI3983DV-T1-E3
 SI3983DV-T1-E3	 SI3983DV-T1-GE3	 SI3983DV-T1-GE3	 SI3991DV-T1-GE3	 SI3993CDV-T1-GE3
 SI3993CDV-T1-GE3	 SI3993DV-T1-E3	 SI3993DV-T1-E3	 SI3993DV-T1-GE3	 SI3993DV-T1-GE3

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